

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/662,433		09/16/2003	Wen-Ching Chen	MR1683-703	9840		
4586	7590	01/12/2006		EXAM	EXAMINER		
	•	LEIN & LEE	WILLIAM	WILLIAMS, DON J			
3458 ELLICOTT CENTER DRIVE-SUITE 101 ELLICOTT CITY, MD 21043				ART UNIT	PAPER NUMBER		
	·			2878			
				DATE MAILED: 01/12/2006			

Please find below and/or attached an Office communication concerning this application or proceeding.

|--|

	Application No.	Applicant(s)		
	10/662,433	CHEN, WEN-CHING		
Office Action Summary	Examiner	Art Unit		
	Don Williams	2878		
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address		
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period of - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a repty be tim vill apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	l. the mailing date of this communication. (35 U.S.C. § 133).		
Status				
1) Responsive to communication(s) filed on Septe	ember 16, 2003.			
2a) ☐ This action is FINAL . 2b) ☑ This	action is non-final.			
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits				
closed in accordance with the practice under E	Ex parte Quayle, 1935 C.D. 11, 45	33 O.G. 213.		
Disposition of Claims				
4) Claim(s) 1-10 is/are pending in the application. 4a) Of the above claim(s) is/are withdray 5) Claim(s) is/are allowed. 6) Claim(s) 1-10 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/o	wn from consideration.			
Application Papers				
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 16 September 2003 is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex	are: a)⊠ accepted or b)⊡ object drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).		
Priority under 35 U.S.C. § 119				
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Application rity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage		
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:			

DETAILED ACTION

Applicant's arguments with respect to claims 1-10 have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 5-7 are rejected under 35 U.S.C. 102(b) as being anticipated by Glenn et al (6,342,406).

As to claim 5 Glenn et al disclose a chip scale package (100) having multiple bumps (112A, 112B) formed on a top face of the semiconductor image sense chip (102) and a transparent layer (140A) attached to the top face of the semiconductor image sense chip (102), and the transparent layer (140A) having a thickness being equal to each of the bumps (112A, 112B), (see figure 3, column 8, lines 1-11).

As to claim 6, Glenn et al disclose a chip scale package (100) with a transparent layer (140A) is a transparent glass plate including multiple penetration holes (118C, 118D), each penetration hole (118C, 118D) aligning with a corresponding one of the multiple bumps (112A, 112B) wherein each bump (112A, 112B) extends to a top face of the transparent glass plate (140A), (see figure 3, column 8, lines 1-11).

Application/Control Number: 10/662,433 Page 3

Art Unit: 2878

As to claim 7, Glenn et al disclose a chip scale package (100) with a transparent layer (140A) being a transparent glass plate having an area equal to that of the semiconductor image sense chip (102), the transparent glass plate (140A) having a periphery (PR) covered by a shelter (130S) to prevent the light from laterally penetrating into the chip scale package structure (100) and influencing the quality of the images collected by the chip scale package structure (100), wherein a metal solder ball (122A, 122B) is planted on a free end of each of the multiple bumps (112A, 112B) and electrically connected to a flexible printed circuit (FPC), the FPC having a window (110) and corresponding to a sensing area (104) of the semiconductor image sense chip (102) and a conducting circuit including multiple first solder points (114) formed near a periphery (PR) of the window (110), the number of the first solder points (114) corresponding to that of the bumps (112A, 112B), the conducting circuit including multiple second solder points (116) formed near one side of the FPC, (see figure 1, column 5, lines 1-5, figure 3, column 7, lines 1-17, column 8, lines 1-11).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-4 and 8-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Glenn et al in view of Park et al (6,211,461).

Art Unit: 2878

As to claim 1, Glenn et al disclose a chip scale package (100) for an image sensor (102) with a semiconductor image sense chip (102), multiple bonding pads (106A, 106B) formed on the top face of the semiconductor image sense chip (102), a conducting wire (118C, 118D) extending from each of the multiple bonding pads (106A, 106B) by wire bonding (114B, 114A), a transparent layer (140A) on the top surface of the semiconductor image sense chip (102) after drying up, the transparent layer (140A) being a single layer structure. Glenn et al fail to explicitly disclose that the liquefied gelatinous material form a transparent layer having a thickness equal to a height of each of the conducting wire. Park et al disclose an epoxy compound (50) dispensed over the semiconductor chip (10) with a thickness equal to a height of each of the conducting wires (40). It would have been obvious for one ordinary skill in the art to use an epoxy compound (50) to cover the entire top plane surface of the semiconductor chip (10) as disclosed by Park et al in order to protect the image semiconductor chip (10) from external contamination such as moisture or dust and therefore improving the durability of the chip scale package (100) allowing it to function at an optimal level due to increased signal response relative to sound conducting wire (40) contact between the circuit board and the semiconductor image chip (10), (see figure 10, column 3, lines 55-67, column 4, lines 1-14).

As to claim 2, Glenn et al disclose a chip scale package (100) with a transparent layer (140A) with a top face parallel to the top face (102F) of the semiconductor image sense chip (102) and a periphery (PR) covered by a shelter (130S) to prevent the light from laterally penetrating into the chip scale package structure (100) and influencing the

Application/Control Number: 10/662,433

Art Unit: 2878

quality of the image that is collected by the chip scale package structure (100), (see figure 3, column 7, lines 1-5).

As to claim 3, Glenn et al disclose a chip scale package (100) with metal solder ball (122A, 122B) is planted on a free end of each of the conducting wires (118C, 118D) and electrically connected to a flexible printed circuit (FPC), the FPC having a window (110) defined and corresponding to a sensing area (104) of the semiconductor image sense chip (102) and a conducting circuit formed on the bottom face of the FPC, the conducting circuit including multiple first solder points (114) formed near a periphery (PR) of the window (110) and the number of the first solder points (114) corresponding to that of the conducting wire (118C, 118D), the conducting circuit having multiple second solder points (116) formed near one side of the FPC, (see figure 1, column 5, lines 5-13, see figure 3, column 8, lines 1-12).

As to claim 4, Glenn et al disclose a chip scale package (100) with second solder points (116, 116B) arranged in an array, (see figure 1).

As to claim 8, Glen et al disclose a chip scale package (100) with a transparent layer (140A) covering the semiconductor image sense chip (102). Glen et al fail to disclose the transparent layer is made from a gelatinous liquefied material. Park et al disclose an epoxy compound (50) dispensed over the semiconductor chip (10). It would have been obvious for one ordinary skill in the art to use an epoxy compound (50) to cover the entire top plane surface of the semiconductor chip (10) as disclosed by Park et al in order to protect the image semiconductor chip (10) from external contamination such as moisture or dust and therefore improving the durability of the chip scale

Application/Control Number: 10/662,433

Art Unit: 2878

package (100) allowing it to function at an optimal level, (see figure 10, column 3, lines 55-67, column 4, lines 1-14).

As to claim 9, Glenn et al disclose a chip scale package (100) with a transparent layer (140A) with a top face parallel to the top face (102F) of the semiconductor image sense chip (102) and a periphery (PR) covered by a shelter (130S) to prevent the light from laterally penetrating into the chip scale package structure (100) and influencing the quality of the image that is collected by the chip scale package structure (100), (see figure 3, column 7, lines 1-5).

As to claim 10, Glenn et al disclose a chip scale package (100) with a metal solder ball (122A, 122B) is planted on a free end of each of the multiple bumps (112A, 112B) and electrically connected to a flexible printed circuit (FPC), the FPC having a window (110) and corresponding to a sensing area (104) of the semiconductor image sense chip (102) and a conducting circuit including multiple first solder points (114) formed near a periphery (PR) of the window (110), the number of the first solder points (114) corresponding to that of the bumps (112A, 112B), the conducting circuit including multiple second solder points (116) formed near one side of the FPC, (see figure 1, column 5, lines 1-5, figure 3, column 7, lines 1-17, column 8, lines 1-11).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Don Williams whose telephone number is 571-272-8538. The examiner can normally be reached on 8:30a.m. to 5:30a.m..

Application/Control Number: 10/662,433 Page 7

Art Unit: 2878

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Georgia Epps can be reached on 571-272-2328. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

tephone B. Allen Frimary Examiner